Product data sheet

1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in an MLPAK33 (SOT8002) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Logic-level compatible
- Trench MOSFET technology
- MLPAK33 package (3.3 x 3.3 mm footprint)

3. Applications

- · DC-to-DC converters
- Battery management
- · Low-side load-switch
- Switching circuits

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{DS}	drain-source voltage	T _j = 25 °C		-	-	30	V
V_{GS}	gate-source voltage			-20	-	20	V
I _D	drain current	V _{GS} = 10 V; T _{amb} = 25 °C; t ≤ 5 s	[1]	-	-	22	Α
Static chara	acteristics			·			
R _{DSon}	drain-source on-state	V _{GS} = 10 V; I _D = 14.2 A; T _j = 25 °C		-	4.6	5.4	mΩ
	resistance	V _{GS} = 4.5 V; I _D = 12.3 A; T _j = 25 °C		-	5.8	7.2	mΩ
Dynamic ch	naracteristics						<u>'</u>
Q _{G(tot)}	total gate charge	V_{DS} = 15 V; I_{D} = 12.3 A; V_{GS} = 4.5 V; T_{j} = 25 °C		-	11.6	17.4	nC

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm².



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5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source	1 2 3 4	D
2	S	source		
3	S	source		G (F)
4	G	gate	l h d	mbb076 S
5	D	drain		
6	D	drain		
7	D	drain	MLPAK33 (SOT8002-1)	
8	D	drain		

6. Ordering information

Table 3. Ordering information

Type number	er Package					
	Name	Description	Version			
PXN5R4-30QL		plastic thermal enhanced surface mounted package; mini leads; 8 terminals; pitch 0.65 mm; 3.3 x 3.3 x 0.8 mm body	SOT8002-1			

7. Marking

Table 4. Marking codes

Type number	Marking code
PXN5R4-30QL	8AP

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8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	30	V
V _{GS}	gate-source voltage			-20	20	V
I _D	drain current	V _{GS} = 10 V; T _{amb} = 25 °C; t ≤ 5 s	[1]	-	22	Α
		V _{GS} = 10 V; T _{amb} = 25 °C	[1]	-	14	Α
		V _{GS} = 10 V; T _{amb} = 100 °C	[1]	-	9	Α
		V _{GS} = 10 V; T _{sp} = 25 °C		-	66	Α
I _{DM}	peak drain current	T _{amb} = 25 °C; single pulse; t _p ≤ 10 μs		-	101	Α
P _{tot}	total power dissipation	T _{amb} = 25 °C; t ≤ 5 s	[1]	-	4.5	W
		T _{amb} = 25 °C	[1]	-	1.8	W
		T _{sp} = 25 °C		-	39	W
Tj	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
Source-drai	n diode		1	'		
I _S	source current	T _{amb} = 25 °C	[1]	-	1.8	Α

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm².

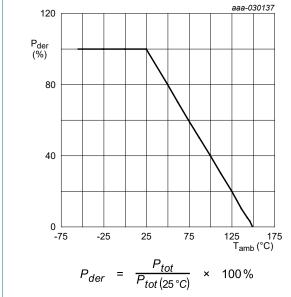


Fig. 1. Normalized total power dissipation as a function of ambient temperature

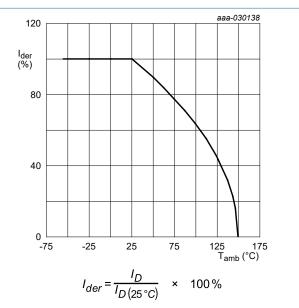


Fig. 2. Normalized continous drain current as a function of ambient temperature

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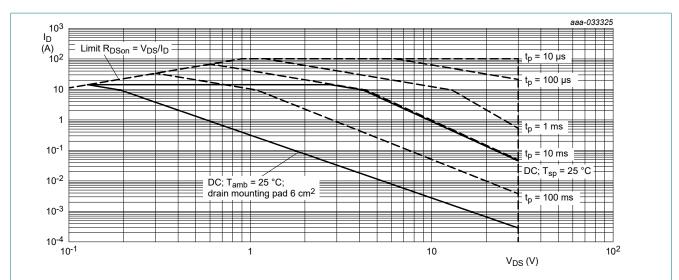


Fig. 3. Safe operating area; junction to ambient; continuous and peak drain currents as a function of drain-source voltage

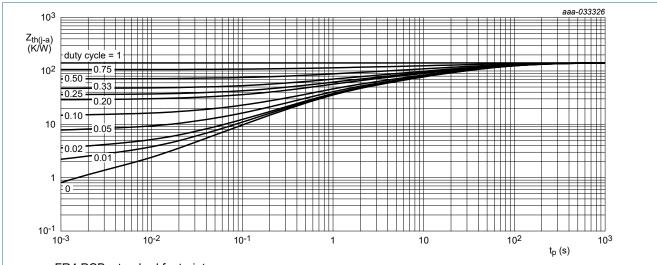
30 V, N-channel Trench MOSFET

9. Thermal characteristics

Table 6. Thermal characteristics

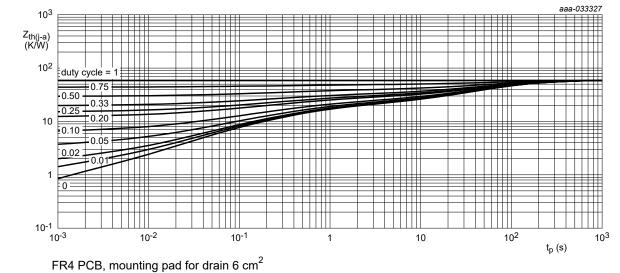
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from	in free air	[1]	-	145	185	K/W
	junction to ambient		[2]	-	55	70	K/W
		in free air; t ≤ 5 s	[2]	-	23	28	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	2.3	3.2	K/W

- Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 6 cm².



FR4 PCB, standard footprint

Transient thermal impedance from junction to ambient as a function of pulse duration; typical values Fig. 4.



Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

30 V, N-channel Trench MOSFET

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics		l			
V _{(BR)DSS}	drain-source breakdown voltage	I _D = 250 μA; V _{GS} = 0 V; T _j = 25 °C	30	-	-	V
V_{GSth}	gate-source threshold voltage	$I_D = 250 \mu A; V_{DS} = V_{GS}; T_j = 25 \text{ °C}$	1	1.6	2.5	V
I _{DSS}	drain leakage current	V _{DS} = 30 V; V _{GS} = 0 V; T _j = 25 °C	-	-	1	μΑ
I _{GSS}	gate leakage current	V _{GS} = 20 V; V _{DS} = 0 V; T _j = 25 °C	-	-	100	nA
		$V_{GS} = -20 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ °C}$	-	-	-100	nA
R _{DSon}	drain-source on-state	V _{GS} = 10 V; I _D = 14.2 A; T _j = 25 °C	-	4.6	5.4	mΩ
	resistance	V _{GS} = 10 V; I _D = 14.2 A; T _j = 150 °C	-	7.5	8.9	mΩ
		$V_{GS} = 4.5 \text{ V}; I_D = 12.3 \text{ A}; T_j = 25 \text{ °C}$	-	5.8	7.2	mΩ
9 _{fs}	forward transconductance	$V_{DS} = 10 \text{ V}; I_D = 14.2 \text{ A}; T_j = 25 \text{ °C}$	-	37	-	S
R _G	gate resistance	f = 1 MHz	-	0.6	-	Ω
Dynamic ch	naracteristics					
Q _{G(tot)}	total gate charge	V_{DS} = 15 V; I_{D} = 14.2 A; V_{GS} = 10 V; T_{j} = 25 °C	-	24.2	36.3	nC
		V _{DS} = 15 V; I _D = 12.3 A; V _{GS} = 4.5 V;	-	11.6	17.4	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	4	-	nC
Q _{GS(th)}	pre-threshold gate- source charge		-	2	-	nC
Q _{GS(th-pl)}	post-threshold gate- source charge		-	2	-	nC
Q _{GD}	gate-drain charge	1	-	3.3	-	nC
V_{GSpl}	gate-source plateau voltage	$V_{DS} = 15 \text{ V}; I_D = 12.3 \text{ A}; T_j = 25 \text{ °C}$	-	2.6	-	V
C _{iss}	input capacitance	V _{DS} = 15 V; f = 1 MHz; V _{GS} = 0 V;	-	1600	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	270	-	pF
C _{rss}	reverse transfer capacitance		-	98	-	pF
t _{d(on)}	turn-on delay time	V _{DS} = 15 V; I _D = 12.3 A; V _{GS} = 4.5 V;	-	9	-	ns
t _r	rise time	$R_{G(ext)} = 5 \Omega$; $T_j = 25 °C$	-	13	-	ns
t _{d(off)}	turn-off delay time	1	-	11	-	ns
t _f	fall time	1	-	5	-	ns
Source-dra	in diode		1		<u> </u>	
V _{SD}	source-drain voltage	I _S = 1.8 A; V _{GS} = 0 V; T _j = 25 °C	-	0.7	1.2	V
t _{rr}	reverse recovery time	$I_S = 1.8 \text{ A}; dI_S/dt = -100 \text{ A/}\mu\text{s};$	-	18	-	ns
Q _r	recovered charge	$V_{GS} = 4.5 \text{ V}; V_{DS} = 15 \text{ V}; T_j = 25 \text{ °C}$	-	11	-	nC
t _a	reverse recovery rise time		-	12	-	ns
t _b	reverse recovery fall time	1	-	6	-	ns

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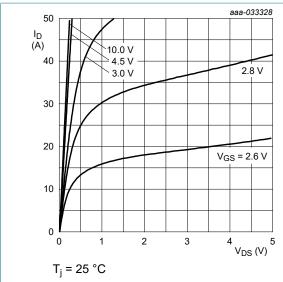


Fig. 6. Output characteristics: drain current as a function of drain-source voltage; typical values

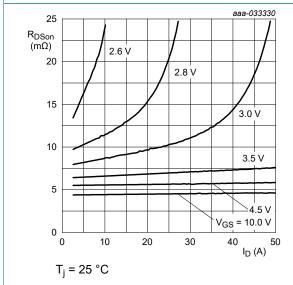


Fig. 8. Drain-source on-state resistance as a function of drain current; typical values

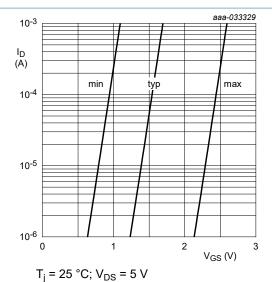


Fig. 7. Subthreshold drain current as a function of

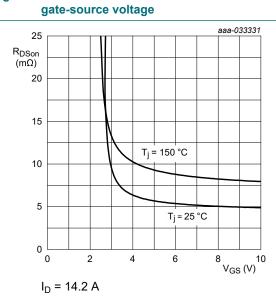


Fig. 9. Drain-source on-state resistance as a function of gate-source voltage; typical values

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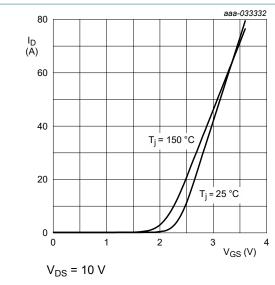


Fig. 10. Transfer characteristics: drain current as a function of gate-source voltage; typical values

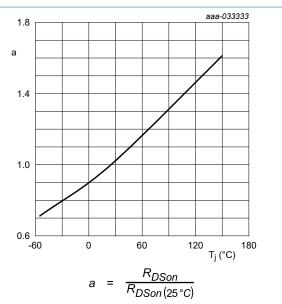


Fig. 11. Normalized drain-source on-state resistance as a function of junction temperature; typical values

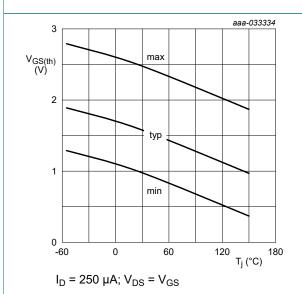


Fig. 12. Gate-source threshold voltage as a function of junction temperature

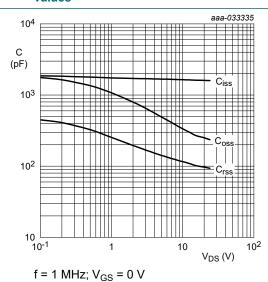


Fig. 13. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

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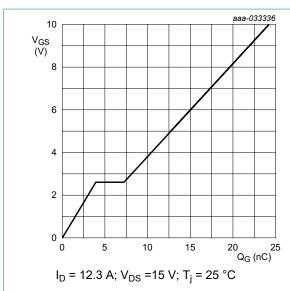


Fig. 14. Gate-source voltage as a function of gate charge; typical values

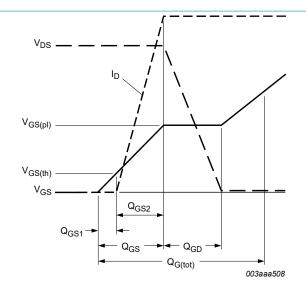


Fig. 15. Gate charge waveform definitions

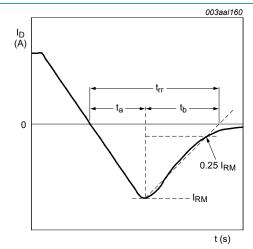


Fig. 16. Reverse recovery timing definition

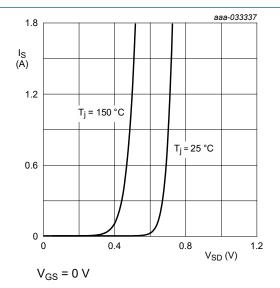
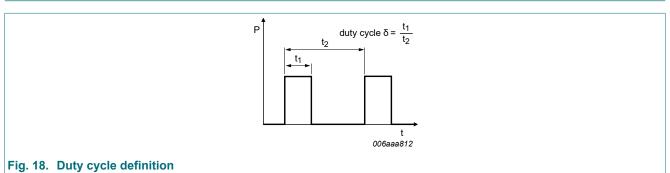


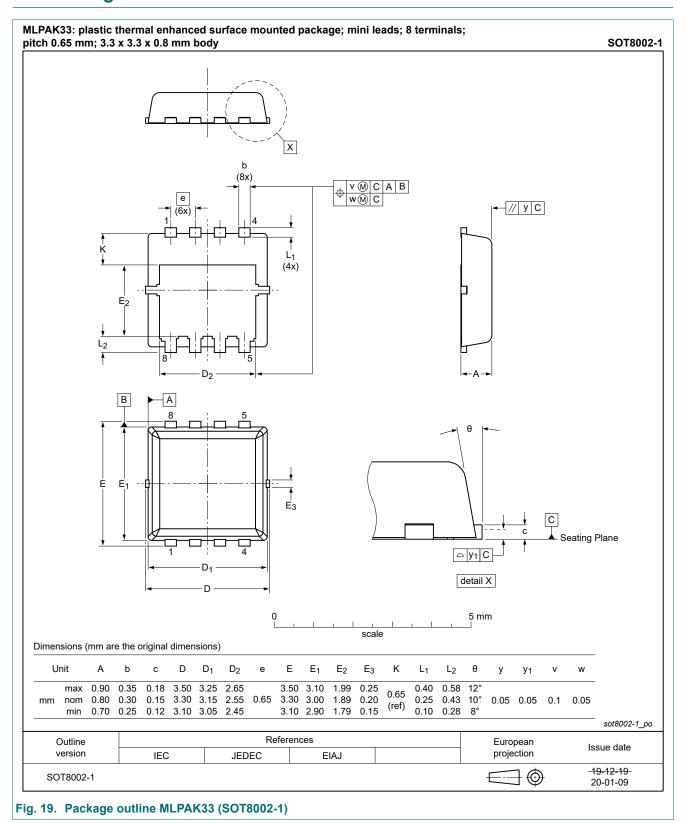
Fig. 17. Source current as a function of source-drain voltage; typical values

11. Test information



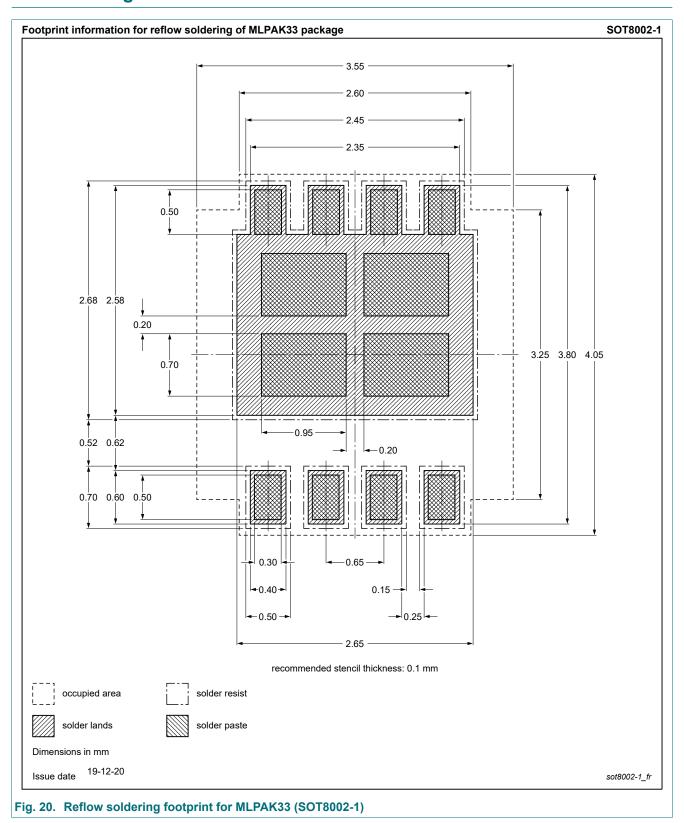
30 V, N-channel Trench MOSFET

12. Package outline



30 V, N-channel Trench MOSFET

13. Soldering



30 V, N-channel Trench MOSFET

14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PXN5R4-30QL v.1	20210415	Product data sheet	-	-

30 V, N-channel Trench MOSFET

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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